# NSN 5962-01-286-1603

Memory Microcircuit - Page 1 of 2



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## Body Length:

1.290 inches

### Body Width:

Between 0.500 inches and 0.610 inches

#### **Body Height:**

Between 0.150 inches and 0.210 inches

#### **Maximum Power Dissipation Rating:**

1.02 watts

#### **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

#### Storage Tempurature Range:

-65.0/+150.0 degrees celsius

#### **Features Provided:**

Hermetically sealed and burn in and programmable and schottky and w/active pull-up and electrostatic sensitive

#### Inclosure Material:

Ceramic

#### Inclosure Configuration:

Dual-in-line

#### **Output Logic Form:**

Transistor-transistor logic

#### Input Circuit Pattern:

14 input

**Case Outline Source And Designator:** 

D-3 mil-m-38510

#### **Terminal Surface Treatment:**

Solder

#### Voltage Rating And Type Per Characteristic:

-0.5 volts power source and 7.0 volts power source

#### Time Rating Per Chacteristic:

100.00 nanoseconds propagation delay time, low to high level output and 100.00 nanoseconds propagation delay time, high to low level output

## Memory Device Type:

Rom

#### Memory Capacity:

Unknown

#### **Test Data Document:**

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

#### **Terminal Type And Quantity:**

24 printed circuit

#### Shelf Life:

N/a

#### Unit Of Measure:

# NSN 5962-01-286-1603

Memory Microcircuit - Page 2 of 2

### Demilitarization:

Yes - demil/mli

Fiig:

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